

Grant Number	Title of Research	Principal Investigator	Research Collaborator of RIEC
H30/A01	Advaced Devices Researches by Using Spatio-Temporal X-ray spectroscopy	FUKIDOME Hirokazu Research Institute of Electrical Communication, Tohoku University	FUKIDOME Hirokazu
H30/A02	Creation of Bio-Medical Devices Using Gas-Liquid Interfacial Plasmas	KANEKO Toshiro Graduate School of Engineering, Tohoku University	HIRANO Ayumi
H30/A03	Quantum devices based on atomic layers	MASUBUCHI Satoru Institute of Industrial Science, University of Tokyo	OTSUKA Tomohiro
H30/A04	Japan-Russia International collaborative research on gated GaAs structures with an array of self- assembled Sn-nanothreads and their terahertz applications	DMITRY Ponomarev Institute of ultra high frequency semiconductor electronics of Russian academy of sciences, Laboratory of high-power microwave and mm-wave applications	OTSUJI Taiichi
H30/A05	Development of vibrational spectroscopy having high temporal and spatial resolution and its application to devices	UEHARA Yoichi Research Institute of Electrical Communication, Tohoku University	UEHARA Yoichi
H30/A06	Development of general control techniques of quantum systems	FUKUHARA Takeshi Center for Emergent Matter Science, RIKEN	OTSUKA Tomohiro
H30/A07	Control of spin state in semiconductor using photon-spin conversion	ISHIHARA Jun Department of Applied Physics, Faculty of Science, Tokyo University of Science	KANAI Shun
H30/A08	Nanoscale optical measurement and ultimate photoelectronic control of carbon nanomaterials	KATANO Satoshi Research Institute of Electrical Communication, Tohoku University	KATANO Satoshi
H30/A09	Informatics approaches in quantum devices	SHIGA Motoki Faculty of Engineering, Gifu University	OTSUKA Tomohiro
H30/A10	Development of Low-Energy Plasma Process for High-Performance Group- IV Semiconductor Quantum Nanodevices	SAKURABA Masao Research Institute of Electrical Communication, Tohoku University	SAKURABA Masao